PI74FCT821T/823T/825T
(25Ω Series) PI74FCT2821T/2823T

Fast CMOS
Bus Interface Registers

Product Features:

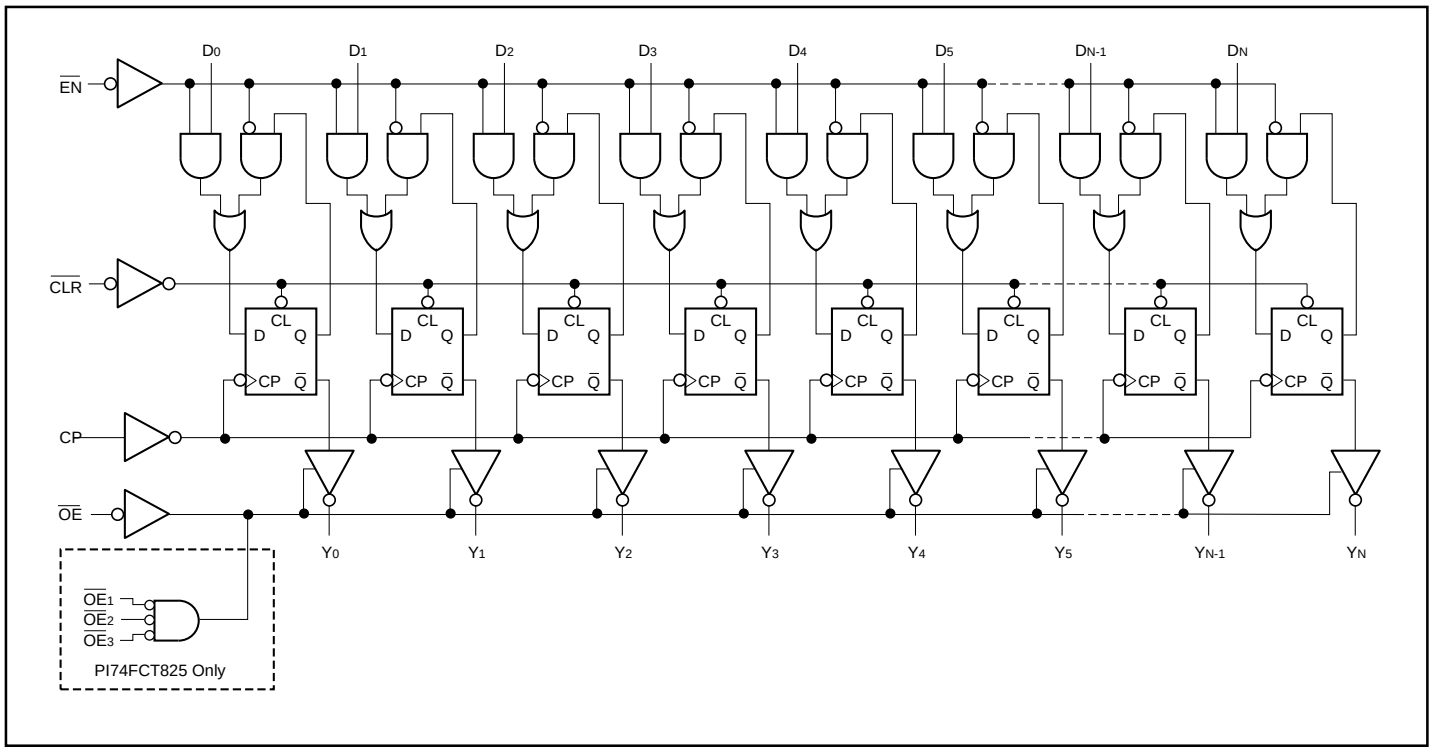
- PI74FCT821T/823T/825T/2821T/2823T is pin compatible with bipolar FAST™ Series at a higher speed and lower power consumption
- 25Ω series resistor on all outputs (FCT2XXX only)
- TTL input and output levels
- Low ground bounce outputs
- Extremely low static power
- Hysteresis on all inputs
- Industrial operating temperature range: –40°C to +85°C
- Packages available:
  - 24-pin 300 mil wide plastic DIP (P)
  - 24-pin 150 mil wide plastic QSOP (Q)
  - 24-pin 150 mil wide plastic TQSOP (R)
  - 24-pin 300 mil wide plastic SOIC (S)
- Device models available upon request

Product Description:

Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.8 micron CMOS technology, achieving industry leading speed grades. All PI74FCT2XXX devices have a built-in 25-ohm series resistor on all outputs to reduce noise because of reflections, thus eliminating the need for an external terminating resistor.

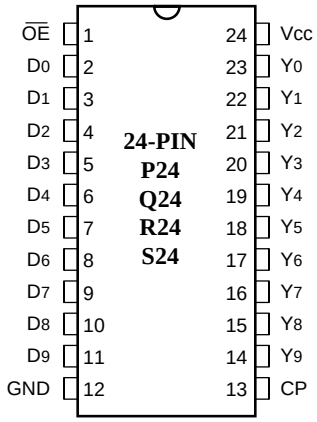
The PI74FCT821T/2821T is a 10-bit wide register designed with ten D-type flip-flops with a buffered common clock and buffered 3-state outputs. The PI74FCT823/2823T is a 9-bit wide register designed with Clock Enable and Clear. The PI74FCT825T is an 8-bit wide register with all PI74FCT823T controls plus multiple enables. When output enable ($\overline{OE}$) is LOW, the outputs are enabled. When $\overline{OE}$ is HIGH, the outputs are in the high impedance state. Input data meeting the setup and hold time requirements of the D inputs is transferred to the Y outputs on the LOW-to-HIGH transition of the clock input.

Logic Block Diagram



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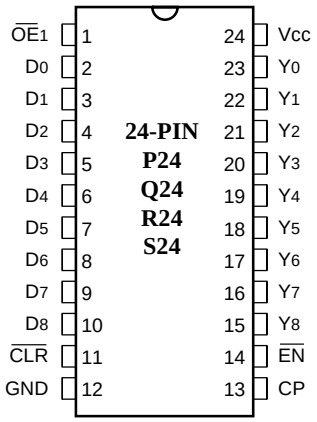
PI74FCT821/2821T Product Pin Configuration



Product Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
CP	Clock Pulse for the register. Enters data on LOW-to-HIGH transition
DN	Data Inputs
YN	3-State Outputs
$\overline{CLR}$	Clear Input (Active LOW) (823/825/2823 Only)
$\overline{EN}$	Clock Enable Input (Active LOW)
GND	Ground
VCC	Power

PI74FCT823/2823T Product Pin Configuration

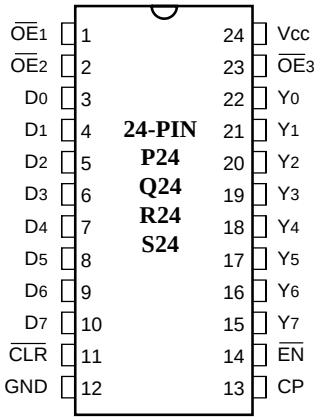


PI74FCT821/823/825/2821/2823T Truth Table[1]

	Inputs					Outputs	Internal
Function	$\overline{CLR}$	$\overline{EN}$	$\overline{OE}$	CP	DN	YN	QN
High-Z	H	L	H	↑	L	Z	L
	H	L	H	↑	H	Z	H
Clear	L	X	H	X	X	Z	L
	L	X	L	X	X	L	L
Hold	H	H	H	X	X	Z	NC
	H	H	L	X	X	NC	NC
Load	H	L	H	↑	L	Z	L
	H	L	H	↑	H	Z	H
	H	L	L	↑	L	L	L
	H	L	L	↑	H	H	H

1. H = High Voltage Level
   L = Low Voltage Level
   X = Don't Care
   Z = High Impedance
   NC = No Change
   ↑ = LOW-to-HIGH transition

PI74FCT825T Product Pin Configuration



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only)	–0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)	–0.5V to +7.0V
DC Input Voltage	–0.5V to +7.0V
DC Output Current	120 mA
Power Dissipation	0.5W

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, T_A = –40°C to +85°C, V_{CC} = 5.0V ± 5%)

Parameters	Description	Test Conditions[1]		Min.	Typ[2]	Max.	Units
V_{OH}	Output HIGH Voltage	V_{CC} = Min., V_{IN} = V_{IH} or V_{IL}	I_{OH} = –15.0 mA	2.4	3.0		V
V_{OL}	Output LOW Current	V_{CC} = Min., V_{IN} = V_{IH} or V_{IL}	I_{OL} = 48 mA		0.3	0.50	V
V_{OL}	Output LOW Current	V_{CC} = Min., V_{IN} = V_{IH} or V_{IL}	I_{OL} = 12 mA (25Ω Series)		0.3	0.50	V
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW Level				0.8	V
I_{IH}	Input HIGH Current	V_{CC} = Max.	V_{IN} = V_{CC}			1	µA
I_{IL}	Input LOW Current	V_{CC} = Max.	V_{IN} = GND			–1	µA
I_{OZH}	High Impedance	V_{CC} = Max.	V_{OUT} = 2.7V			1	µA
I_{OZL}	Output Current		V_{OUT} = 0.5V			–1	µA
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_{IN} = –18 mA			–0.7	–1.2	V
I_{OFF}	Power Down Disable	V_{CC} = GND, V_{OUT} = 4.5V		—	—	100	µA
I_{OS}	Short Circuit Current	V_{CC} = Max.[3], V_{OUT} = GND		–60	–120		mA
V_H	Input Hysteresis				200		mV

Capacitance (T_A = 25°C, f = 1 MHz)

Parameters[4]	Description	Test Conditions	Typ	Max.	Units
C_{IN}	Input Capacitance	V_{IN} = 0V	6	10	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	8	12	pF

Notes:
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at Vcc = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. This parameter is determined by device characterization but is not production tested.

Power Supply Characteristics

Parameters	Description	Test Conditions[1]		Min.	Typ[2]	Max.	Units
I_{CC}	Quiescent Power Supply Current	V_{CC} = Max.	V_{IN} = GND or V_{CC}		0.1	500	µA
ΔI_{CC}	Supply Current per Input @ TTL HIGH	V_{CC} = Max.	V_{IN} = 3.4V[3]		0.5	2.0	mA
I_{CCD}	Supply Current per Input per MHz[4]	V_{CC} = Max., Outputs Open $\overline{OE}$ = $\overline{EN}$ = GND One Input Toggling 50% Duty Cycle	V_{IN} = V_{CC} V_{IN} = GND		0.15	0.25	mA/ MHz
I_C	Total Power Supply Current[6]	V_{CC} = Max., Outputs Open f_{CP} = 10 MHz 50% Duty Cycle $\overline{OE}$ = $\overline{EN}$ = GND f_I = 5 MHz One Bit Toggling	V_{IN} = V_{CC} V_{IN} = GND		1.5	3.5[5]	mA
			V_{IN} = 3.4V V_{IN} = GND		2.0	5.5[5]	
		V_{CC} = Max., Outputs Open f_{CP} = 10 MHz 50% Duty Cycle $\overline{OE}$ = $\overline{EN}$ = GND Eight Bits Toggling f_I = 2.5 MHz 50% Duty Cycle	V_{IN} = V_{CC} V_{IN} = GND		3.8	7.3[5]	
			V_{IN} = 3.4V V_{IN} = GND		6.0	16.3[5]	

Notes:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at Vcc = 5.0V, +25°C ambient.
3. Per TTL driven input (V_{IN} = 3.4V); all other inputs at Vcc or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.
6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
   $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$
   I_{CC} = Quiescent Current
   ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4 V)
   D_H = Duty Cycle for TTL Inputs High
   N_T = Number of TTL Inputs at D_H
   I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
   f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)
   f_I = Input Frequency
   N_I = Number of Inputs at f_I
   All currents are in milliamps and all frequencies are in megahertz.

PI74FCT821/2821T Switching Characteristics over Operating Range

Parameters	Description	Conditions[1]	821AT/2821AT Com. Min	821AT/2821AT Com. Max	821BT/2821BT Com. Min	821BT/2821BT Com. Max	821CT/2821CT Com. Min	821CT/2821CT Com. Max	Unit
t_{PLH} t_{PHL}	Propagation Delay CP to Y_N ($\overline{OE}$ = LOW)	C_L = 50 pF R_L = 500Ω	1.5	10.0	1.5	7.5	1.5	6.0	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	20.0	1.5	15.0	1.5	12.5	ns
t_{SU}	Setup Time HIGH or LOW, D_N to CP	C_L = 50 pF R_L = 500Ω	4.0	—	3.0	—	3.0	—	ns
t_H	Hold Time HIGH or LOW, D_N to CP		2.0	—	1.5	—	1.5	—	ns
t_{SU}	Setup Time HIGH or LOW, $\overline{EN}$ to CP		4.0	—	3.0	—	3.0	—	ns
t_H	Hold Time HIGH or LOW, $\overline{EN}$ to CP		2.0	—	0	—	0	—	ns
t_{PHL}	Propagation Delay, $\overline{CLR}$ to Y_N		1.5	14.0	1.5	9.0	1.5	8.0	ns
t_{REM}	Recovery Time,[3] $\overline{CLR}$ to CP		6.0	—	6.0	—	6.0	—	ns
t_W	Clock Pulse Width[3] HIGH or LOW		7.0	—	5.0	—	6.0	—	ns
t_W	$\overline{CLR}$ Pulse Width[3] LOW		6.0	—	6.0	—	6.0	—	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to Y_N	C_L = 50 pF R_L = 500Ω	1.5	11.5	1.5	8.0	1.5	7.0	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	23.0	1.5	15.0	1.5	12.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time[3] $\overline{OE}$ to Y_N	C_L = 50 pF R_L = 500Ω	1.5	7.0	1.5	6.5	1.5	6.2	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	8.0	1.5	7.5	1.5	6.5	ns

Notes:
1. See test circuit and wave forms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. This parameter is guaranteed but not production tested.

PI74FCT823/2823T Switching Characteristics over Operating Range

Parameters	Description	Conditions[1]	823AT/2823AT Com. Min	823AT/2823AT Com. Max	823BT/2823BT Com. Min	823BT/2823BT Com. Max	823CT/2823CT Com. Min	823CT/2823CT Com. Max	Unit
t_{PLH} t_{PHL}	Propagation Delay CP to Y_N ($\overline{OE}$ = LOW)	C_L = 50 pF R_L = 500Ω	1.5	10.0	1.5	7.5	1.5	6.0	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	20.0	1.5	15.0	1.5	12.5	ns
t_{SU}	Setup Time HIGH or LOW, D_N to CP	C_L = 50 pF R_L = 500Ω	4.0	—	3.0	—	3.0	—	ns
t_H	Hold Time HIGH or LOW, D_N to CP		2.0	—	1.5	—	1.5	—	ns
t_{SU}	Setup Time HIGH or LOW, $\overline{EN}$ to CP		4.0	—	3.0	—	3.0	—	ns
t_H	Hold Time HIGH or LOW, $\overline{EN}$ to CP		2.0	—	0	—	0	—	ns
t_{PHL}	Propagation Delay, $\overline{CLR}$ to Y_N		1.5	13.0	1.5	9.0	1.5	8.0	ns
t_{REM}	Recovery Time,[3] $\overline{CLR}$ to CP		6.0	—	6.0	—	6.0	—	ns
t_W	Clock Pulse Width [3] HIGH or LOW		7.0	—	5.0	—	6.0	—	ns
t_W	$\overline{CLR}$ Pulse Width [3] LOW		6.0	—	6.0	—	6.0	—	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to Y_N	C_L = 50 pF R_L = 500Ω	1.5	11.5	1.5	8.0	1.5	7.0	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	23.0	1.5	15.0	1.5	12.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time[3] $\overline{OE}$ to Y_N	C_L = 50 pF R_L = 500Ω	1.5	7.0	1.5	6.5	1.5	6.2	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	8.0	1.5	7.5	1.5	6.5	ns

Notes:
1. See test circuit and wave forms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. This parameter is guaranteed but not production tested.

PI74FCT825T Switching Characteristics over Operating Range

Parameters	Description	Conditions[1]	825AT Com. Min	825AT Com. Max	825BT Com. Min	825BT Com. Max	825CT Com. Min	825CT Com. Max	Unit
t_{PLH} t_{PHL}	Propagation Delay CP to Y_N ($\overline{OE}$ = LOW)	C_L = 50 pF R_L = 500Ω	1.5	10.0	1.5	7.5	1.5	6.0	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	20.0	1.5	15.0	1.5	12.5	ns
t_{SU}	Setup Time HIGH or LOW, D_N to CP	C_L = 50 pF R_L = 500Ω	4.0	—	3.0	—	3.0	—	ns
t_H	Hold Time HIGH or LOW, D_N to CP		2.0	—	1.5	—	1.5	—	ns
t_{SU}	Setup Time HIGH or LOW, $\overline{EN}$ to CP		4.0	—	3.0	—	3.0	—	ns
t_H	Hold Time HIGH or LOW, $\overline{EN}$ to CP		2.0	—	0	—	0	—	ns
t_{PHL}	Propagation Delay, $\overline{CLR}$ to Y_N		1.5	13.0	1.5	9.0	1.5	8.0	ns
t_{REM}	Recovery Time, $\overline{CLR}$ to CP		6.0	—	6.0	—	6.0	—	ns
t_W	Clock Pulse Width HIGH or LOW		7.0	—	5.0	—	6.0	—	ns
t_W	$\overline{CLR}$ Pulse Width[3] LOW		6.0	—	6.0	—	6.0	—	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to Y_N	C_L = 50 pF R_L = 500Ω	1.5	11.5	1.5	8.0	1.5	7.0	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	23.0	1.5	15.0	1.5	12.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time[3] $\overline{OE}$ to Y_N	C_L = 50 pF R_L = 500Ω	1.5	7.0	1.5	6.5	1.5	6.2	ns
		C_L = 300 pF[3] R_L = 500Ω	1.5	8.0	1.5	7.5	1.5	6.5	ns

Notes:
1. See test circuit and wave forms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. This parameter is guaranteed but not production tested.